

MHW612

The RF Line

VHF POWER AMPLIFIER MODULE

. . . designed for 12.5 volt VHF power amplifier applications in industrial and commercial FM equipment operating to 174 MHz

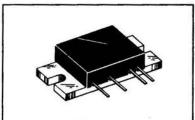
- Frequency Range 146 to 174 MHz
- Specified 12.5 Volt, VHF Characteristics Output Power = 20 Watts Minimum Gain = 20 dB Harmonics = -30 dB
- 50 Ω Input/Output Impedances
- Guaranteed Stability and Ruggedness
- Gain Control Pin for Manual or Automatic Output Level Control
- Thin-Film Hybrid Construction Gives Consistent Performance and Reliability

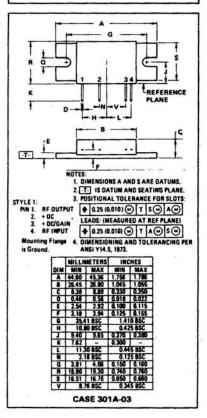
MAXIMUM RATINGS (Flange Temperature = 25°C)

Rating	Symbol	Value	Unit
DC Supply Voltages	V _s , V _{sc}	16	Vdc
RF Input Power	Pin	400	mW
RF Output Power (V _S = V _{SC} = 12.5 V)	Pout	30	w
Storage Temperature Range	T _{stg}	-65 to +125	°C
Operating Case Temperature Range	TC	-30 to +100	°C

20 W - 146-174 MHz

RF POWER
AMPLIFIER MODULE

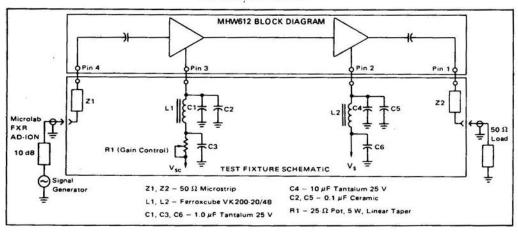




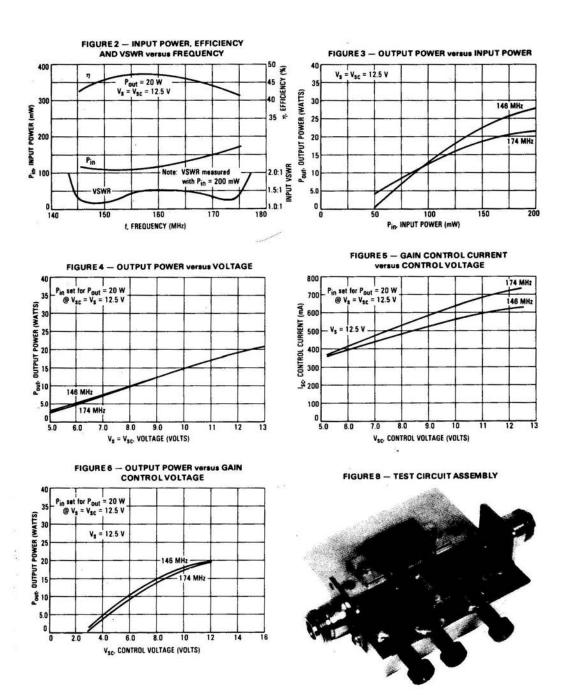
ELECTRICAL CHARACTERISTICS (Flange Temperature = 25°C, 50 Ω system, and V_S = V_{SC} = 12.5 V unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit		
Frequency Range	BW	146	_	174	MHz		
Input Power (Pout = 20 W)	Pin	=	-	200	mW		
Power Gain (Pout = 20 W)	Gp	20	-	-	dB		
Efficiency (Pout = 20 W)	η	40	-	_	%		
Harmonic Output (P _{Out} = 20 W Reference)	-	-	-	-30	dB		
Input Impedance (Pin = 200 mW, 50 Ω Reference, V _{SC} set for P _{OUt} = 20 W)	Zin	-	_	2:1	VSWR		
Power Degradation (-30 to +90°C) (Pin = 200 mW, V _{SC} set for P _{OUt} = 20 W @ T _C = 25°C)	_	-	-	1.0	dB		
Load Mismatch Stress (V _S = V _{SC} = 15.5 Vdc, P _{Out} = 30 W. VSWR = 30:1, all phase angles)	-	No degradation in Power Output					
Stability 1. (P _{in} = 100 to 300 mW, V _S = V _{SC} = 9.5 to 15.5 V P _{out} ≤ 30 W, Load VSWR = 3:1) 2. (V _S = 12.5 V, V _{SC} = 0 to 12.5 V, P _{in} = 200 mW, Load VSWR = 3:1)	All spurious outputs ≽70 dB below the desired output signal level						

FIGURE 1 - TEST CIRCUIT



MHW612



APPLICATIONS INFORMATION

Nominal Operation

All electrical specifications are based on the following nominal conditions: ($P_{in} = 200 \text{ mW}$, $V_{s} = 12.5 \text{ V}$, V_{sc} adjusted to $20 \text{ W } P_{out}$). These modules are designed to have excess gain margin with ruggedness, but operation outside the limits of published specifications is not recommended unless prior communications regarding intended use has been made with a factory representative.

Gain Control

In general, the module output power should be limited to 25 watts. For best performance over temperature, optimum efficiency, and input VSWR, the module input power should be set to 200 mW and V_{SC} adjusted for the rated 20 watt output power. This condition will also tend to be the most stable under varying supply voltage and load mismatch conditions. V_{SC} is best controlled through a stiff voltage source.

Decoupling

Due to the high gain of each of the two stages and the module size limitation, external decoupling networks require careful consideration. Both Pins 2 and 3 are internally bypassed with a 0.018 μ F chip capacitor effective for frequencies of 5 MHz through 174 MHz. For bypassing frequencies below 5 MHz, networks equivalent to that shown in the test figure schematic are recommended. Inadequate decoupling will result in spurious outputs at specific operating frequencies and phase angles of input and output VSWR less than 4:1.

Load Pull

During final test, each module is "load pull" tested in a fixture having the identical decoupling network described in Figure 1. Electrical conditions are V_S and V_{SC} equal to 15.5 volts output, VSWR 30:1 and output power equal to 30 watts.

RF Input

RF Output

ORF Output

ONE Outpu

FIGURE 7 - VHF POWER MODULE TEST FIXTURE PRINTED CIRCUIT BOARD

See Figure 1 for component values.